## NSN 5962-01-376-0661

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-376-0661

**Body Length:** 1.280 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Programmed and electrostatic sensitive and monolithic and high impedance and w/clock and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Case Outline Source And Designator:** D-9 mil-m-38510 **Current Rating Per Characteristic:** 210.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** Registered and-or gate array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 12.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, high to low level output and 30.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Pal

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 printed circuit

Shelf Life:

N/a

**Unit Of Measure:** 

## NSN 5962-01-376-0661

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

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